

Features

- ◆ Transient protection for data lines to **IEC 61000-4-2 (ESD) ±20kV (air), ±20kV (contact)**
IEC 61000-4-4 (EFT) 40A (tp = 5/50ns)
Cable Discharge Event (CDE)
- ◆ Ultra-small package (1.0 x 0.6 x 0.5mm)
- ◆ Protects one data or I/O line
- ◆ Low capacitance: **0.35pF**
- ◆ Low clamping voltage
- ◆ Low operating voltage: 5.0V
- ◆ Solid-state silicon-avalanche technology

Mechanical Characteristics

- ◆ Package: DFN1006-2 (0402)
- ◆ Lead Finish: Matte Tin
- ◆ UL Flammability Classification Rating 94V-0
- ◆ Pb-Free, Halogen Free, RoHS/WEEE Compliant



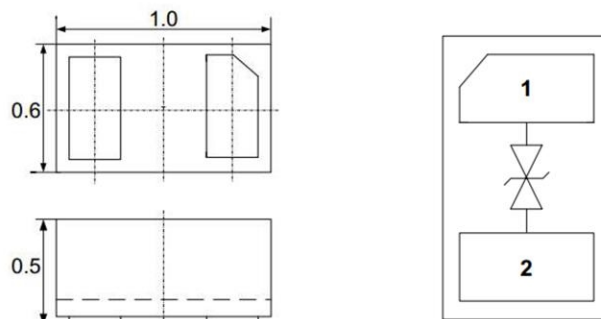
Applications

- ◆ Cellular Handsets & Accessories
- ◆ Digital Visual Interface (DVI)
- ◆ Display Port
- ◆ MDDI Ports
- ◆ USB Ports
- ◆ PCI Express
- ◆ Serial ATA

Ordering Information

Part Number	Qty per Reel	Reel Size
TPESDLC0521P	3000 Or 10000	7"

Dimensions and Pin Configuration

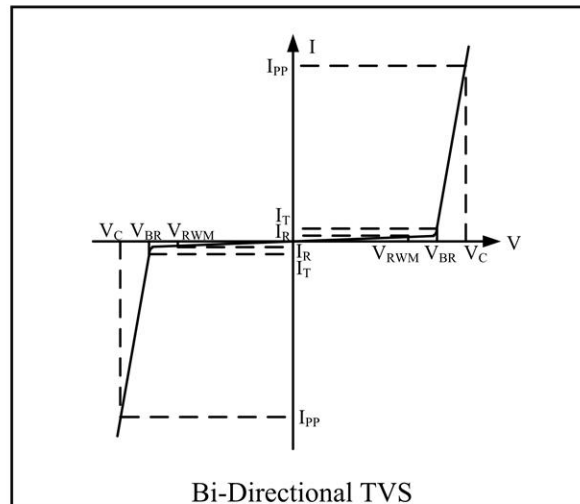


Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μs)	Ppk	100	W
Peak Pulse Current (8/20 μs)	I _{PP}	4	A
ESD per IEC 61000-4-2 (Air)	VESD	± 20	kV
ESD per IEC 61000-4-2 (Contact)		± 20	
Operating Temperature Range	T _J	-55 to +125	$^\circ\text{C}$
Storage Temperature Range	T _{stg}	-55 to +150	$^\circ\text{C}$

Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter
V _{RWM}	Nominal Reverse Working Voltage
I _R	Reverse Leakage Current @ V _{RWM}
V _{BR}	Reverse Breakdown Voltage @ I _T
I _T	Test Current for Reverse Breakdown
V _C	Clamping Voltage @ I _{PP}
I _{PP}	Maximum Peak Pulse Current
C _{ESD}	Parasitic Capacitance
V _R	Reverse Voltage
f	Small Signal Frequency



Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}			5	V	
Breakdown Voltage	V _{BR}	6			V	I _T = 1mA
Reverse Leakage Current	I _R			0.3	μA	V _{RWM} = 5V
Clamping Voltage	V _C			10	V	I _{PP} = 1A (8 x 20 μs pulse)
Clamping Voltage	V _C			25	V	I _{PP} = 4A (8 x 20 μs pulse)
Junction Capacitance	C _J		0.35	0.5	pF	V _R = 0V, f = 1MHz

Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise Specified)

Fig1. 8/20 μs Pulse Waveform

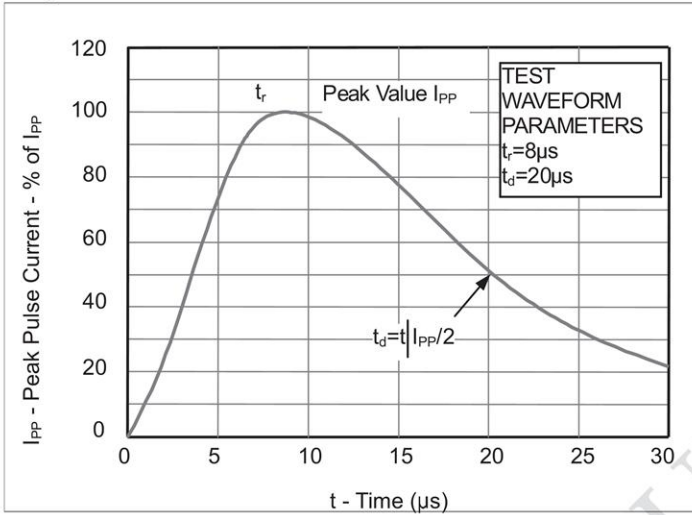


Fig2. ESD Pulse Waveform (according to IEC 61000-4-2)

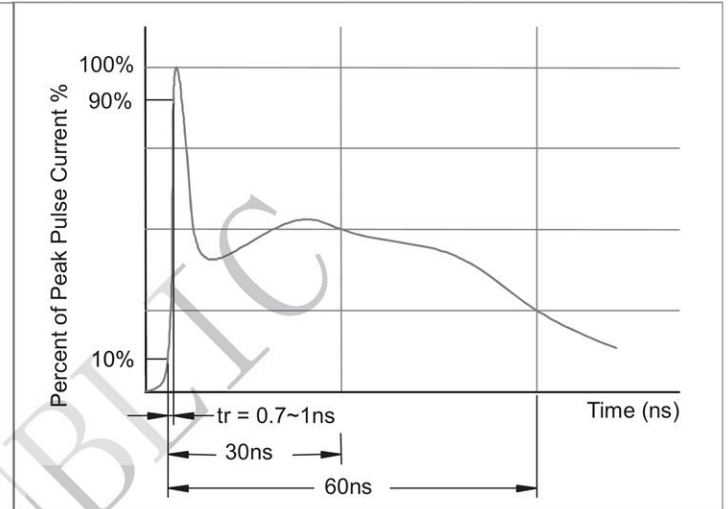
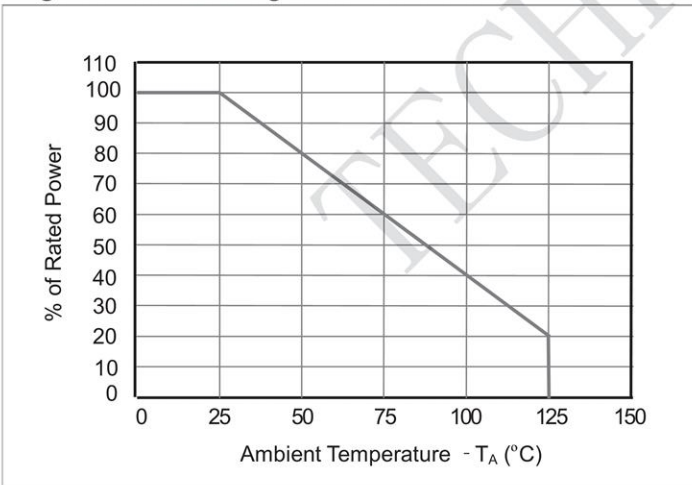
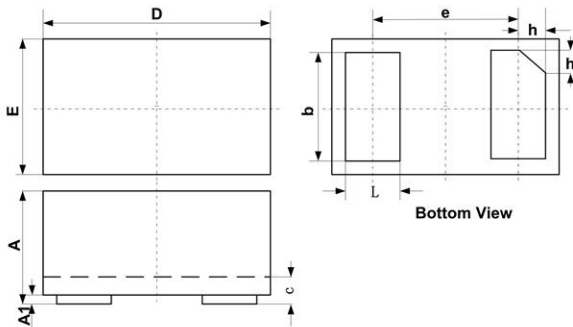


Fig3. Power Derating Curve

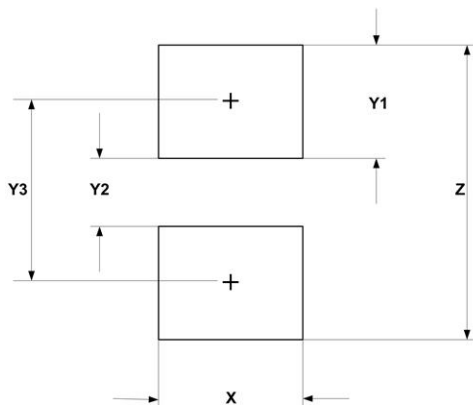


Outline Drawing - DFN1006-2



SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.45	0.50	0.55	0.018	0.020	0.022
c	0.12	0.15	0.18	0.005	0.006	0.007
D	0.95	1.00	1.05	0.037	0.039	0.041
e	0.65 BSC			0.026 BSC		
E	0.55	0.60	0.65	0.022	0.024	0.026
L	0.20	0.25	0.30	0.008	0.010	0.012
h	0.07	0.12	0.17	0.003	0.005	0.007

Land Pattern - DFN1006-2



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
X	0.60	0.024
Y1	0.50	0.020
Y2	0.30	0.012
Y3	0.80	0.032
Z	1.30	0.052